

RoHS

COMPLIANT

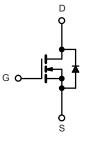
N-Channel 60 V (D-S) Super Junction Power MOSFET

PRODUCT SUMMARY					
V _{DS} (V)	$V_{DS}(V)$ $R_{DS(on)}(\Omega)$ $I_{D}(A)$				
60	0.0035 at V _{GS} = 10 V	130			
	0.0042 at V _{GS} = 4.5 V	110			

TO-220 Pin Configuration



Top View



FEATURES

• 175 °C Junction Temperature

• DT-SJ Power MOSFET

• Material categorization:

N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS (T _C = 25 °C, unless otherwise noted)							
Parameter	Symbol	Limit	Unit				
Gate-Source Voltage	V _{GS}	± 20	V				
Continuous Drain Current (T 175 °C) ^b	T _C = 25 °C	1_	130				
Continuous Drain Current (T _J = 175 °C) ^b	T _C = 100 °C	D ID	110 ^a				
Pulsed Drain Current	I _{DM}	480	A				
Continuous Source Current (Diode Conduction)	۱ _S	110 ^a					
Avalanche Current	I _{AS}	110					
Single Avalanche Energy (Duty Cycle \leq 1 %)	E _{AS}	500	mJ				
Maximum Power Dissipation	T _C = 25 °C	P _D	180	w			
	T _A = 25 °C	'D	3 ^b , 8.5 ^{b, c}	vv			
Operating Junction and Storage Temperature Range	T _J , T _{stg}	- 55 to 175	°C				

THERMAL RESISTANCE RATINGS							
Parameter		Symbol	Typical	Maximum	Unit		
Maximum Junction-to-Ambient ^a	$t \le 10 \text{ sec}$	R _{thJA}	15	18	°C/W		
Maximum Junction-to-Ambient*	Steady State	'` thJA	40	50			
Maximum Junction-to-Case		R _{thJC}	0.85	1.1			

Notes:

a. Package limited.

b. Surface mounted on 1" x 1" FR4 board.

c. t \leq 10 s.

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SPECIFICATIONS (T _J = 25 °C, unless otherwise noted)								
Parameter	Symbol	Test Conditions	Min.	Typ. ^a	Max.	Unit		
Static								
Drain-Source Breakdown Voltage	V _{DS}	V _{GS} = 0 V, I _D = 250 μA	60			V		
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = 250 \ \mu A$	1		3	v		
Gate-Body Leakage	I _{GSS}	V_{DS} = 0 V, V_{GS} = ± 20 V			± 100	nA		
		V _{DS} = 48 V, V _{GS} = 0 V			1	μA		
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 48 V, V _{GS} = 0 V, T _J = 125 °C			50			
		V_{DS} = 48 V, V_{GS} = 0 V, T_{J} = 175 °C			250			
On-State Drain Current ^b	I _{D(on)}	V _{DS} = 5 V, V _{GS} = 10 V	130			А		
		V _{GS} = 10 V, I _D = 20 A		0.0035	0.0040	0		
	P	V _{GS} = 10 V, I _D = 20 A, T _J = 125 °C		0.0040	0.0050			
Drain-Source On-State Resistance ^b	R _{DS(on)}	V _{GS} = 10 V, I _D = 10 A, T _J = 175 °C		0.0045	0.0055	Ω		
		V _{GS} = 4.5 V, I _D = 15 A		0.0042	0.0050	-		
Forward Transconductance ^b	9 _{fs}	V _{DS} = 48 V, I _D = 20 A		50		S		
Dynamic	•							
Input Capacitance	C _{iss}			3950		pF		
Output Capacitance	C _{oss}	V_{GS} = 0 V, V_{DS} = 48 V, f = 1 MHz		670				
Reverse Transfer Capacitance	C _{rss}			23				
Total Gate Charge ^c	Qg			67	78			
Gate-Source Charge ^c	Q _{gs}	V_{DS} = 48 V, V_{GS} = 10 V, I_D = 20 A		12		nC		
Gate-Drain Charge ^c	Q _{gd}			8.5				
Turn-On Delay Time ^c	t _{d(on)}			10	20			
Rise Time ^c	t _r	V_{DD} = 48 V, R_{L} = 0.6 Ω		5	15	20		
Turn-Off Delay Time ^c	t _{d(off)}	$\text{I}_\text{D}\cong$ 20 A, V_GEN = 10 V, Rg = 2.5 Ω		55	70	ns		
Fall Time ^c				12	20			
Source-Drain Diode Ratings and Cha	aracteristics (T _C = 25 °C)	•		· · · · · · · · · · · · · · · · · · ·			
Pulsed Current	I _{SM}				130	А		
Diode Forward Voltage	V _{SD}	I _F = 20 A, V _{GS} = 0 V		1	1.2	V		
Reverse Recovery Time	t _{rr}	I _F = 20 A, di/dt = 100 A/μs		45	100	ns		

Notes:

a. For design aid only; not subject to production testing.

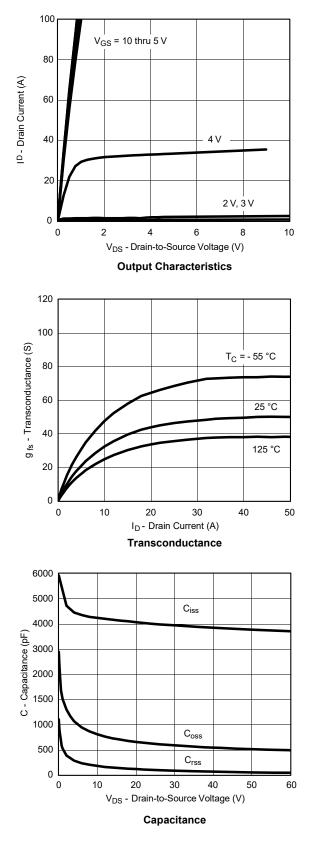
b. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

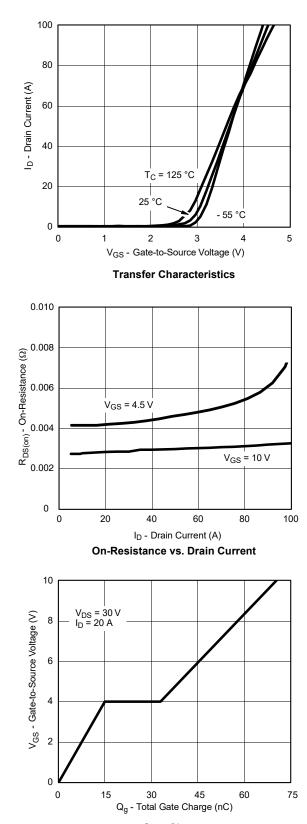
c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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TYPICAL CHARACTERISTICS (25 °C unless noted)

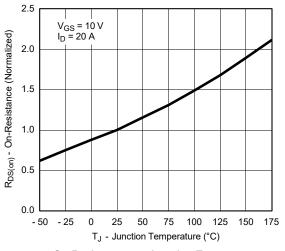




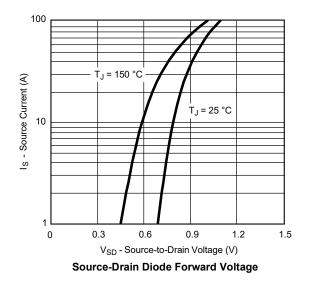
Gate Charge

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TYPICAL CHARACTERISTICS (25 °C unless noted)



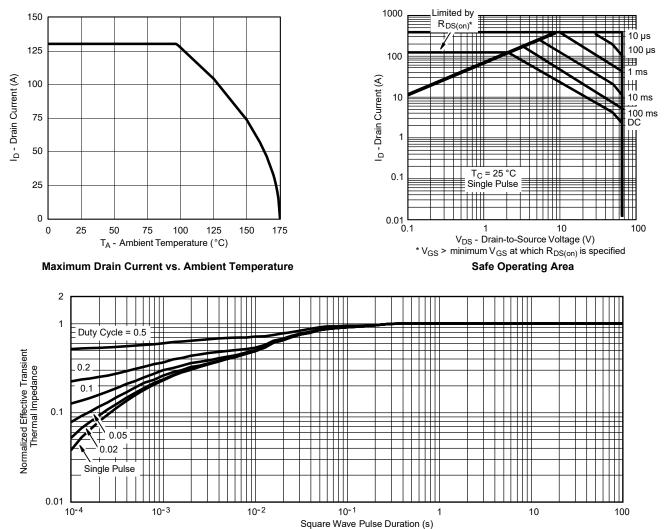
On-Resistance vs. Junction Temperature





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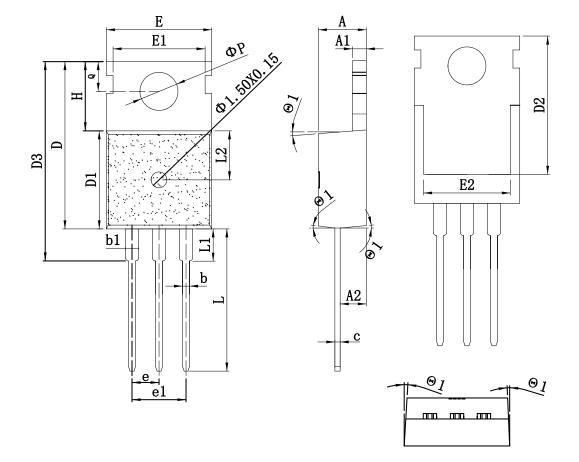
THERMAL RATINGS



Normalized Thermal Transient Impedance, Junction-to-Case



TO-220_3L-A PACKAGE OUTLINE

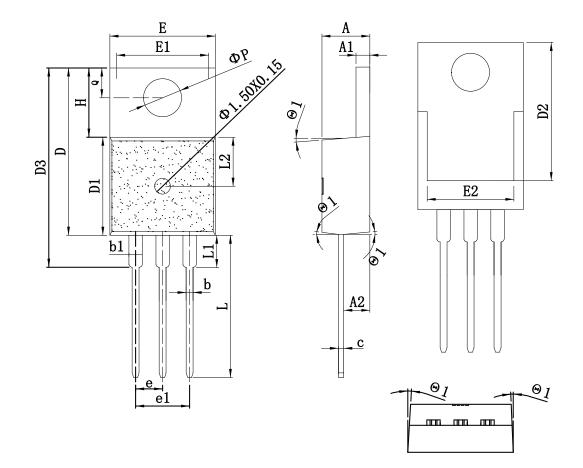


COMMON DIMENSIONS (UNITS OF MEASURE=MILLIMETER)

SYMBOL		mm		SYMPOL	SYMBOL mm			
SIMBOL	MIN	TYP	MAX	SIMBOL	MIN	TYP	MAX	
А	4.15	4.50	4.80	E1	8.25	8.70	9.15	
A1	1.15	1.30	1.50	E2	7.20	8.00	8.80	
A2	2.10	2.40	2.65	e	2.38	2.54	2.74	
b	0.65	0.80	1.00	e1	5.08REF			
b1	1.10	1.33	1.80	Н	6.20	6.50	6.90	
с	0.35	0.50	0.65	L	12.75	13.28	13.70	
D	14.25	15.75	16.15	L1	-	-	3.50	
D1	8.70	9.20	9.60	L2	2.30	4.65	7.00	
D2	12.30	13.10	13.85	φP	3.40	3.65	3.85	
D3	16.20	18.80	20.60	Q	2.50	2.80	3.00	
Е	8.68	10.02	11.00	θ	2°	-	7°	



TO-220_3L-B PACKAGE OUTLINE



COMMON DIMENSIONS (UNITS OF MEASURE=MILLIMETER)

SYMBOL		mm		SYMBOL	MBOI			
SIMBOL	MIN	TYP	MAX	SIMBOL	MIN	TYP	MAX	
А	4.15	4.50	4.80	E1	8.25	8.70	9.15	
A1	1.15	1.30	1.50	E2	7.20	8.00	8.80	
A2	2.10	2.40	2.65	e	2.38	2.54	2.74	
b	0.65	0.80	1.00	e1	5.08REF			
b1	1.10	1.33	1.80	Н	6.20	6.50	6.90	
с	0.35	0.50	0.65	L	12.75	13.28	13.70	
D	14.25	15.75	16.15	L1	-	-	3.50	
D1	8.70	9.20	9.60	L2	2.30	4.65	7.00	
D2	12.30	13.10	13.85	φP	3.40	3.65	3.85	
D3	16.20	18.80	20.60	Q	2.50	2.80	3.00	
Е	8.68	10.02	11.00	θ	2°	-	7°	



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